





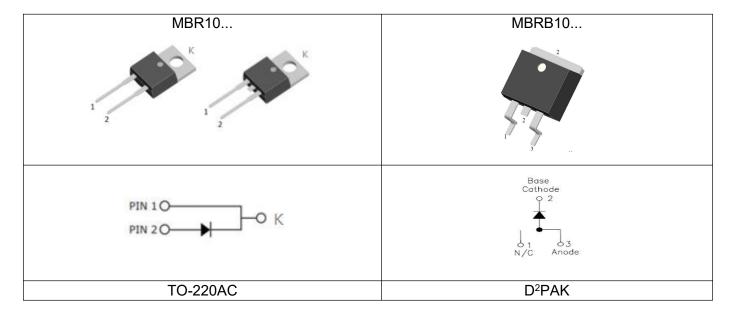
MBR1035/MBR1045/MBRB1035/MBRB1045 SCHOTTKY RECTIFIER

Features

- 150[°]C T_J operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- · High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection



Maximum Ratings@Tc=25°C unless otherwise specified

| Characteristics | Symbol | Condition | | Max. | Units |
|---|--|------------------------|----|-----------|---------------------------------------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage | V _{RRM} | - | 35 | (MBR1035) | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ |
| DC Blocking Voltage | $egin{array}{c} V_{RWM} \ V_{R} \end{array}$ | | 45 | (MBR1045) | V |
| Average Rectified Forward Current | I _{F (AV)} | Tc=133°C, In DC | | 10 | Α |
| Peak One Cycle Non-Repetitive Surge Current | I _{FSM} | 8.3ms, Half Sine pulse | | 150 | А |

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Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|------------------------|-----------------|--|------|--------|-------|
| Forward Voltage Drop* | V _{F1} | @10A, Pulse, T _J = 25 ℃ | 0.56 | 0.84 | V |
| | V _{F2} | @10A, Pulse, T _J = 125 ℃ | 0.51 | 0.72 | V |
| Reverse Current * | I _{R1} | $@V_R = \text{rated } V_R$ $T_J = 25 \ ^{\circ}C$ | 0.02 | 0.1 | mA |
| | I _{R2} | $@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}C$ | 9 | 15 | mA |
| Junction Capacitance | Ст | $@V_R = 5V, T_C = 25 \degree C$ $f_{SIG} = 1MHz$ | 320 | 800 | pF |
| Series Inductance | Ls | Measured lead to lead 5 mm from package body | 8.0 | - | nH |
| Voltage Rate of Change | dv/dt | - | - | 10,000 | V/µs |

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

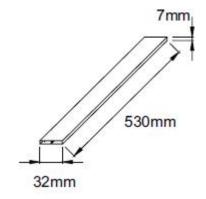
| Characteristics | Symbol | Condition | Specification | Units |
|---|-----------------------------|--------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +150 | °C |
| Storage Temperature | T _{stg} | - | -55 to +150 | °C |
| Typical Thermal Resistance Junction to Case | $R_{	heta JC}$ | DC operation | 2.0 | °C/W |
| Case Style | TO-220AC D ² PAK | | | |

Tube Specification

| Device | Package | Weight | Shipping |
|--------|----------|--------|---------------|
| MBR10 | TO-220AC | 1.8g | 50pcs / tube |
| MBRB10 | D² PAK | 1.85g | 800pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AC)









Ratings and Characteristics Curves

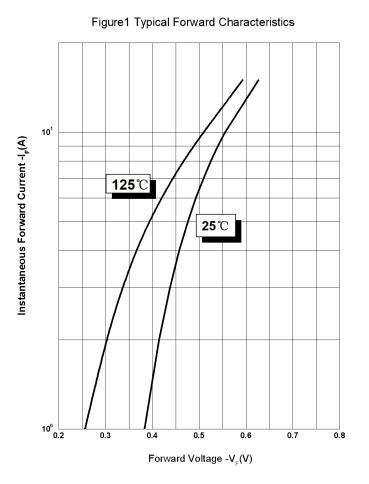
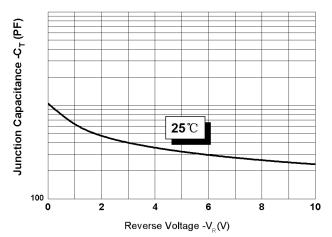


Figure 2 Typical Reverse Characteristics

10²
10³

Figure 3 Typical Junction Capacitance





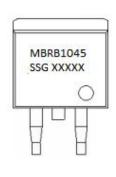






Marking Diagram





Where XXXXX is YYWWL

 MBR
 = Device Type

 B
 = Package type

 10
 = Forward Current (10A)

 35/45
 = Reverse Voltage (35/45V)

 SSG
 = SSG

 YY
 = Year

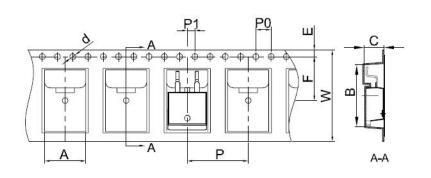
 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Carrier Tape Specification D²PAK



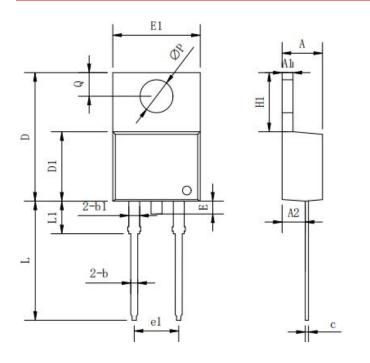
| Symbol | Millimeters | | | |
|---------|-------------|-------|--|--|
| Зуппоот | Min. | Max. | | |
| Α | 10.70 | 10.90 | | |
| В | 16.03 | 16.23 | | |
| С | 5.11 | 5.31 | | |
| d | 1.45 | 1.65 | | |
| E | 1.65 | 1.85 | | |
| F | 11.40 | 11.60 | | |
| P0 | 3.90 | 4.10 | | |
| Р | 15.90 | 16.10 | | |
| P1 | 1.90 | 2.10 | | |
| W | 23.90 | 24.30 | | |





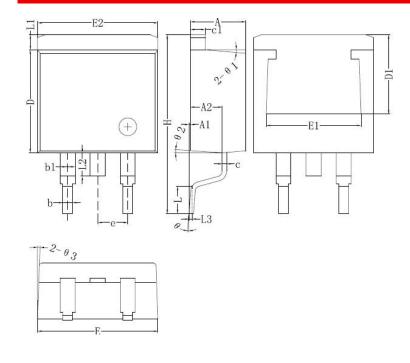


Mechanical Dimensions TO-220AC



| Symbol | Dimensions in millimeters | | |
|--------|---------------------------|---------|-------|
| | Min. | Typical | Max. |
| Α | 3.56 | - | 4.83 |
| A1 | 0.51 | - | 1.4 |
| A2 | 2.03 | - | 2.92 |
| b | 0.38 | - | 1.02 |
| b1 | 1.14 | - | 1.78 |
| С | 0.31 | - | 0.61 |
| D | 14.22 | - | 16.51 |
| D1 | 8.38 | - | 9.42 |
| E | - | - | 1.78 |
| E1 | 9.65 | 10.16 | 10.67 |
| e1 | - | 5.08 | - |
| H1 | 5.84 | - | 6.86 |
| L | 12.7 | - | 14.73 |
| L1 | - | - | 6.35 |
| ФР | - | 3.56 | - |
| Q | 2.54 | - | 3.43 |

Mechanical Dimensions D²PAK



| Symbol | Dimensions in millimeters | | |
|----------|---------------------------|-------|--|
| Syllibol | Min. | Max. | |
| Α | 4.06 | 4.83 | |
| A1 | 0 | 0.26 | |
| b | 0.51 | 0.99 | |
| b1 | 1.14 | 1.78 | |
| С | 0.31 | 0.74 | |
| c1 | 1.14 | 1.65 | |
| D | 8.38 | 9.65 | |
| D1 | 6.4 | | |
| E1 | 6.22 | | |
| E2 | 9.65 | 10.67 | |
| е | 2.54BSC | | |
| Н | 14.6 | 15.88 | |
| L | 1.78 | 2.8 | |
| L1 | - | 1.68 | |
| L2 | - 2.2 | | |
| L3 | 0.255BSC | | |
| Θ | 0 8° | | |

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